

Gallium Arsenide CATV Amplifier Module

Features

- Specified for 79-, 112- and 132-Channel Loading
- Excellent Distortion Performance
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

- CATV Systems Operating in the 40 to 1000 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Output Stage Amplifier on Applications Requiring Low Power Dissipation and High Output Performance
- Driver Amplifier in Linear General Purpose Applications

Description

- 24 Vdc Supply, 40 to 1000 MHz, CATV GaAs Forward Amplifier Module
- RoHS Compliant

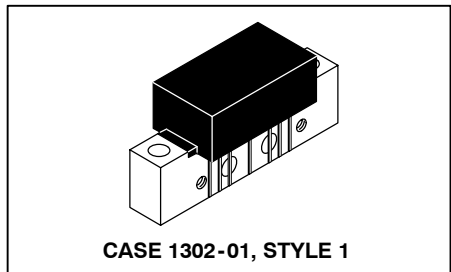
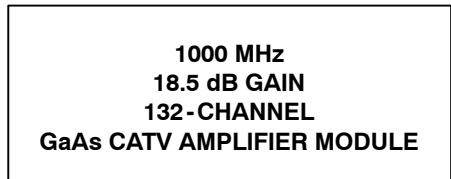


Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V_{in}	+65	dBmV
DC Supply Voltage	V_{CC}	+26	Vdc
Operating Case Temperature Range	T_C	-20 to +100	°C
Storage Temperature Range	T_{stg}	-40 to +100	°C

Table 2. ESD Maximum Ratings

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	300	300	V
Human Body Model per Mil. Std. 1686	2	2	kV

Table 3. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = +30^\circ\text{C}$, 75 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	40	—	1000	MHz
Power Gain 1000 MHz	G_p	18	18.5	19.5	dB
Slope 40-1000 MHz	S	0.2	0.6	1.2	dB
Gain Flatness (40-1000 MHz, Peak-to-Valley)	G_F	—	0.3	0.8	dB
Return Loss — Input ($Z_o = 75$ Ohms)	IRL				dB
40-200 MHz		20	—	—	
201-600 MHz		19	—	—	
601-870 MHz		18	—	—	
871-1000 MHz		15	—	—	
Return Loss — Output ($Z_o = 75$ Ohms)	ORL				dB
40-200 MHz		20	—	—	
201-600 MHz		19	—	—	
601-870 MHz		18	—	—	
871-1000 MHz		17	—	—	

ARCHIVE INFORMATION

ARCHIVE INFORMATION

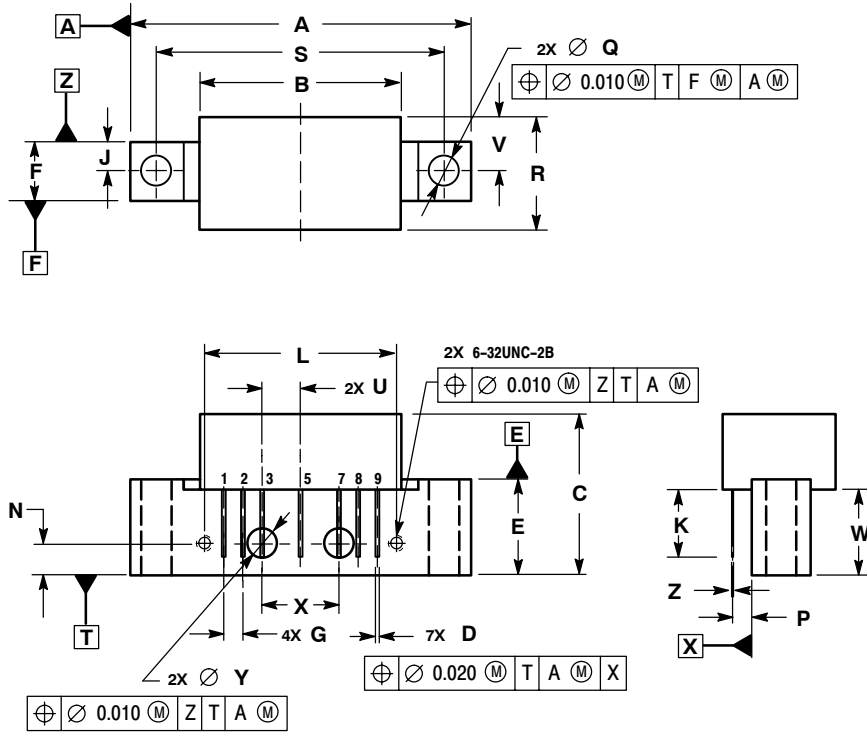
Table 3. Electrical Characteristics ($V_{CC} = 24 \text{ Vdc}$, $T_C = +30^\circ\text{C}$, 75Ω system unless otherwise noted) (continued)

Characteristic		Symbol	Min	Typ	Max	Unit
Composite Second Order ($V_{out} = +48 \text{ dBmV/ch.}$, Worst Case) ($V_{out} = +46 \text{ dBmV/ch.}$, Worst Case) ($V_{out} = +44 \text{ dBmV/ch.}$, Worst Case)	79-Channel FLAT	CSO_{79}	—	-72	-64	dBc
	112-Channel FLAT	CSO_{112}	—	-65	-61	
	132-Channel FLAT	CSO_{132}	—	-67	-60	
Cross Modulation Distortion @ Ch 2 ($V_{out} = +48 \text{ dBmV/ch.}$, FM = 55 MHz) ($V_{out} = +46 \text{ dBmV/ch.}$, FM = 55 MHz) ($V_{out} = +44 \text{ dBmV/ch.}$, FM = 55 MHz)	79-Channel FLAT	XMD_{79}	—	-58	—	dBc
	112-Channel FLAT	XMD_{112}	—	-58	—	
	132-Channel FLAT	XMD_{132}	—	-58	—	
Composite Triple Beat ($V_{out} = +48 \text{ dBmV/ch.}$, Worst Case) ($V_{out} = +46 \text{ dBmV/ch.}$, Worst Case) ($V_{out} = +44 \text{ dBmV/ch.}$, Worst Case)	79-Channel FLAT	CTB_{79}	—	-64	-60	dBc
	112-Channel FLAT	CTB_{112}	—	-61	-58	
	132-Channel FLAT	CTB_{132}	—	-62	-58	
Noise Figure	50 MHz	NF	—	4	5	dB
	870 MHz		—	3.7	5	
	1000 MHz		—	4.1	5	
DC Current ($V_{DC} = 24 \text{ V}$, $T_C = -20^\circ$ to $+100^\circ\text{C}$)		I_{DC}	230	250	265	mA

ARCHIVE INFORMATION

ARCHIVE INFORMATION

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	---	1.775	---	45.085
B	---	1.085	---	27.559
C	---	0.840	---	21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.62	8.255
G	0.100 BSC		2.540 BSC	
J	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165 BSC		4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R	---	0.600	---	15.24
S	1.500 BSC		38.100 BSC	
U	0.200 BSC		5.080 BSC	
V	---	0.250	---	6.350
W	0.435	---	11.049	---
X	0.400 BSC		10.160 BSC	
Y	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01
 ISSUE E

REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
0	Nov. 2006	<ul style="list-style-type: none">Initial Release of Data Sheet

ARCHIVE INFORMATION

ARCHIVE INFORMATION

How to Reach Us:

Home Page:

www.freescale.com

Web Support:

<http://www.freescale.com/support>

USA/Europe or Locations Not Listed:

Freescale Semiconductor, Inc.
 Technical Information Center, EL516
 2100 East Elliot Road
 Tempe, Arizona 85284
 +1-800-521-6274 or +1-480-768-2130
www.freescale.com/support

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
 Technical Information Center
 Schatzbogen 7
 81829 Muenchen, Germany
 +44 1296 380 456 (English)
 +46 8 52200080 (English)
 +49 89 92103 559 (German)
 +33 1 69 35 48 48 (French)
www.freescale.com/support

Japan:

Freescale Semiconductor Japan Ltd.
 Headquarters
 ARCO Tower 15F
 1-8-1, Shimo-Meguro, Meguro-ku,
 Tokyo 153-0064
 Japan
 0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
 Technical Information Center
 2 Dai King Street
 Tai Po Industrial Estate
 Tai Po, N.T., Hong Kong
 +800 2666 8080
support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor Literature Distribution Center
 P.O. Box 5405
 Denver, Colorado 80217
 1-800-441-2447 or 303-675-2140
 Fax: 303-675-2150
LDCForFreescaleSemiconductor@hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.
 © Freescale Semiconductor, Inc. 2006, 2008. All rights reserved.